



## PRELIMINARY DATA SHEET

# 2G bits DDR3L SDRAM

**D2568ECMDPGJD(I)-U (256M words x 8 bits)**

**D2568ECMDPGME-U (256M words x 8 bits)**

**D1216ECMDXGJD(I)-U (128M words x 16 bits)**

**D1216ECMDXGME(I/Y)-U (128M words x 16 bits)**

### Specifications

- Density: 2G bits
- Organization
  - 32Mwords x 8bits x 8banks
  - 16Mwords x 16bits x 8banks
- Package
  - 78-ball FBGA
  - 96-ball FBGA
  - Lead-free (RoHS compliant) and Halogen-free
- Power supply: 1.35V (Typ)
  - VDD, VDDQ = 1.283V to 1.45V
  - Backward compatible for VDD, VDDQ=1.5V  $\pm$  0.075V
- Data rate
  - 2133Mbps/1866Mbps/1600Mbps/1333Mbps (max.)
- 2KB page size
  - Row address: A0 to A13
  - Column address: A0 to A9
- 1KB page size
  - Row address: A0 to A14
  - Column address: A0 to A9
- Eight internal banks for concurrent operation
- Burst lengths (BL): 8 and 4 with Burst Chop (BC)
- Burst type (BT):
  - Sequential (8, 4 with BC)
  - Interleave (8, 4 with BC)
- Programmable /CAS (Read) Latency (CL)
- Programmable /CAS Write Latency (CWL)
- Precharge: auto precharge option for each burst access
- Driver strength: RZQ/7, RZQ/6 (RZQ = 240 $\Omega$ )
- Refresh: auto-refresh, self-refresh
- Refresh cycles
  - Average refresh period
  - 7.8 $\mu$ s at 0°C  $\leq$  Temperature  $\leq$  +85°C
  - 3.9 $\mu$ s at +85°C  $\leq$  Temperature  $\leq$  +105°C
- Operating Case temperature range
  - 0°C to +95°C (Commercial Temperature)
  - -40°C to +95°C (Industrial Temperature)
  - -40°C to +105°C (Automotive Temperature)

### Features

- Double-data-rate architecture: two data transfers per clock cycle
- The high-speed data transfer is realized by the 8 bits prefetch pipelined architecture
- Bi-directional differential data strobe (DQS and /DQS) is transmitted/received with data for capturing data at the receiver
- DQS is edge-aligned with data for READS; center-aligned with data for WRITES
- Differential clock inputs (CK and /CK)
- DLL aligns DQ and DQS transitions with CK transitions
- Commands entered on each positive CK edge; data and data mask referenced to both edges of DQS
- Data mask (DM) for write data
- Posted /CAS by programmable additive latency for better command and data bus efficiency
- On-Die Termination (ODT) for better signal quality
  - Synchronous ODT
  - Dynamic ODT
  - Asynchronous ODT
- Multi Purpose Register (MPR) for pre-defined pattern read out
- ZQ calibration for DQ drive and ODT
- Automatic self refresh (ASR)
- /RESET pin for Power-up sequence and reset function
- SRT range:
  - Normal/extended
- Programmable Output driver impedance control

## Revision History

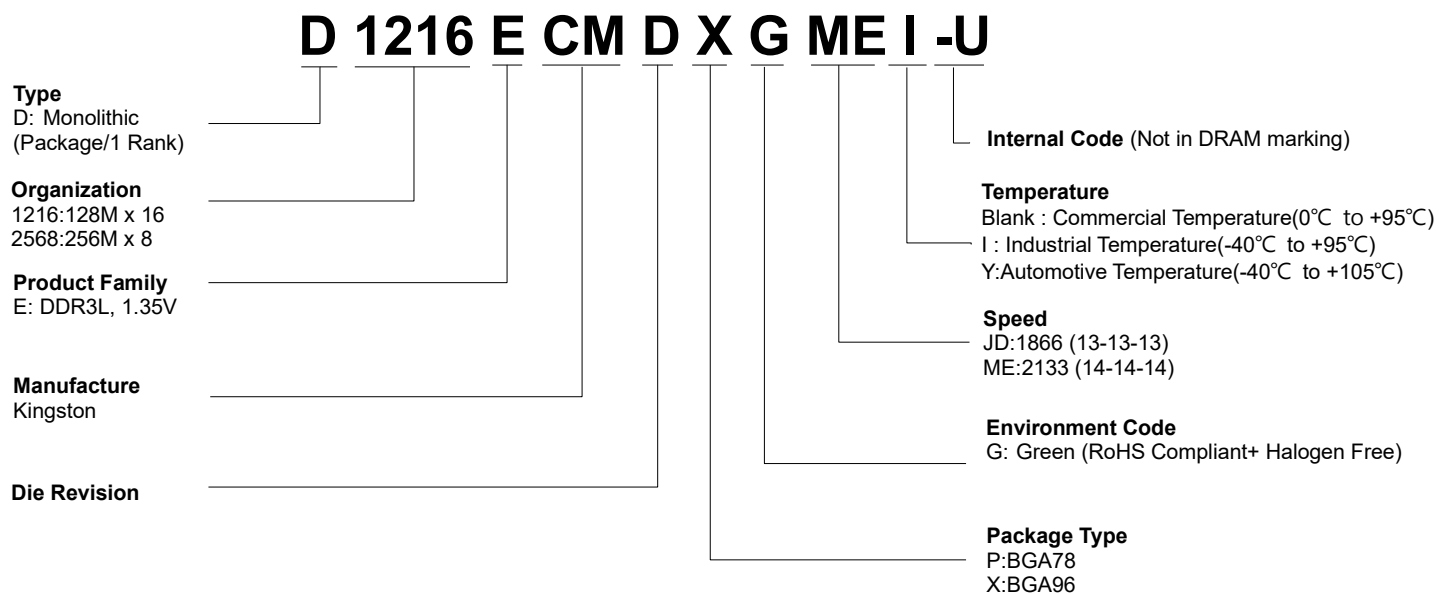
| Revision No. | History         | Release date | Remark                        |
|--------------|-----------------|--------------|-------------------------------|
| 1.0          | Initial release | Feb 2019     |                               |
| 1.1          | Second release  | Mar 2019     | Add Data rate 2133 and I-temp |
| 1.2          | Third release   | Sept 2019    | Add P/N and A-temp            |
| 1.3          | Fourth release  | Nov 2019     | Revise file name              |
| 1.4          | Fifth release   | Nov 2019     | Add P/N                       |
| 1.5          | Sixth release   | Dec 2019     | Add P/N                       |

*\*Products and specifications discussed herein are for evaluation and reference purposes only and are subject to change by without notice.  
All information discussed herein is provided on an "as is" basis, without warranties of any kind.*

## Ordering Information

| Part Number      | Die revision | Organization<br>(words x bits) | Internal<br>Banks | JEDEC speed bin<br>(CL-tRCD-tRP) | Package      |
|------------------|--------------|--------------------------------|-------------------|----------------------------------|--------------|
| D2568ECMDPGJD-U  | D            | 256M x 8                       | 8                 | DDR3L-1866 (13-13-13)            | 78-ball FBGA |
| D2568ECMDPGJDI-U |              |                                |                   |                                  |              |
| D2568ECMDPGME-U  | D            | 256M x 8                       | 8                 | DDR3L-2133 (14-14-14)            | 78-ball FBGA |
| D1216ECMDXGJD-U  | D            | 128M x 16                      | 8                 | DDR3L-1866 (13-13-13)            | 96-ball FBGA |
| D1216ECMDXGJDI-U |              |                                |                   |                                  |              |
| D1216ECMDXGME-U  | D            | 128M x 16                      | 8                 | DDR3L-2133 (14-14-14)            | 96-ball FBGA |
| D1216ECMDXGMEI-U |              |                                |                   |                                  |              |
| D1216ECMDXGMEY-U |              |                                |                   |                                  |              |

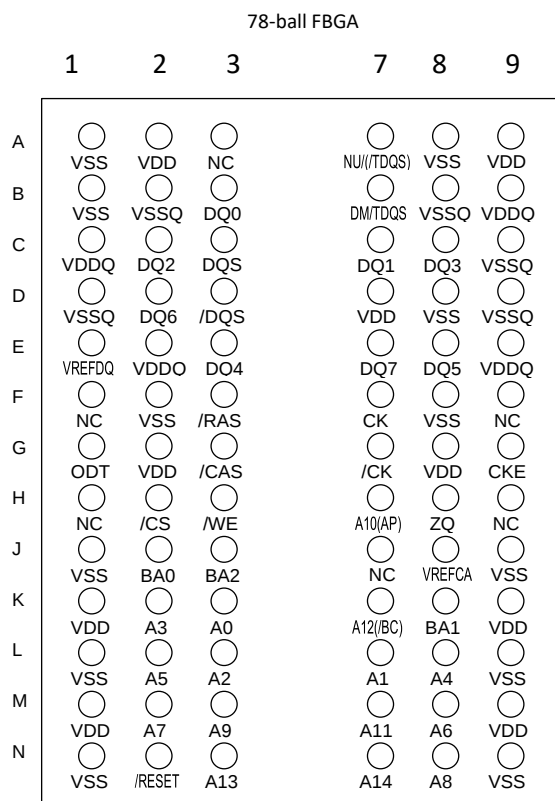
### Part Number



## Pin Configurations

### Pin Configurations ( x8 configuration)

/xxx indicates active low signal



| Pin                           | Function                                                           |
|-------------------------------|--------------------------------------------------------------------|
| A0 to A14 <sup>*3</sup>       | Address inputs<br>A10(AP) : Auto precharge<br>A12(BC) : Burst chop |
| BA0 to BA2 <sup>*3</sup>      | Bank select                                                        |
| DQ0 to DQ7                    | Data input/output                                                  |
| DQS, /DQS                     | Differential data strobe                                           |
| TDQS, /TDQS                   | Termination data strobe                                            |
| /CS <sup>*3</sup>             | Chip select                                                        |
| /RAS, /CAS, /WE <sup>*3</sup> | Command input                                                      |
| CKE <sup>*3</sup>             | Clock enable                                                       |
| CK, /CK                       | Differential clock input                                           |
| DM                            | Write data mask                                                    |
| ODT <sup>*3</sup>             | ODT control                                                        |

| Pin name             | Function                            |
|----------------------|-------------------------------------|
| /RESET <sup>*3</sup> | Active low asynchronous reset       |
| VDD                  | Supply voltage for internal circuit |
| VSS                  | Ground for internal circuit         |
| VDDQ                 | Supply voltage for DQ circuit       |
| VSSQ                 | Ground for DQ circuit               |
| VREFDQ               | Reference voltage for DQ            |
| VREFCA               | Reference voltage for CA            |
| ZQ                   | Reference pin for ZQ calibration    |
| NC <sup>*1</sup>     | No connection                       |
| NU <sup>*2</sup>     | Not usable                          |

Notes : 1. Not internally connected with die.

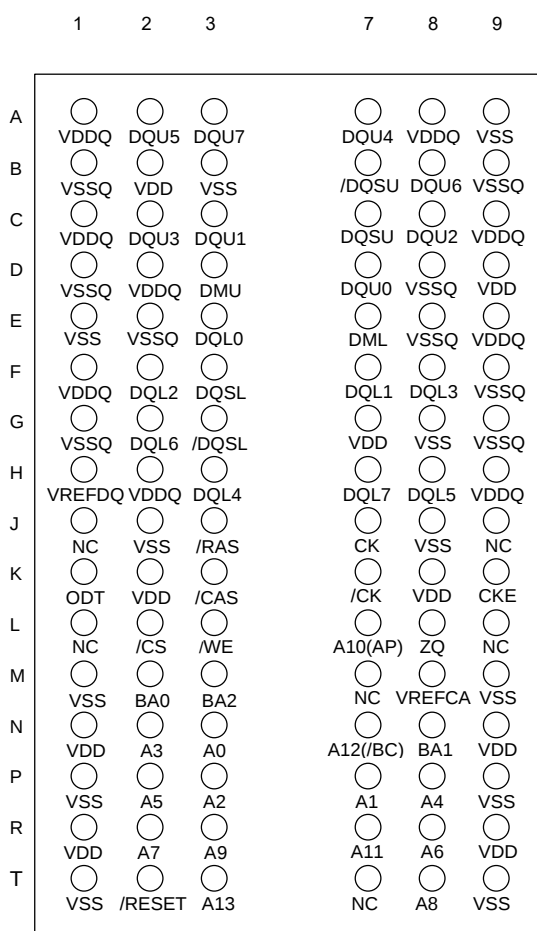
2. Don't connect Internally connected.

3. Input only pins (address, command, CKE, ODT and /RESET) do not supply termination

## Pin Configurations ( x16 configuration)

/xxx indicates active low signal

96-ball FBGA



(Top view)

| Pin                           | Function                                                            |
|-------------------------------|---------------------------------------------------------------------|
| A0 to A13 <sup>*2</sup>       | Address inputs<br>A10(AP) : Auto precharge<br>A12(/BC) : Burst chop |
| BA0 to BA2 <sup>*2</sup>      | Bank select                                                         |
| DQU0 to DQU7<br>DQL0 to DQL7  | Data input/output                                                   |
| DQSU, /DQSU<br>DQSL, /DQSL    | Differential data strobe                                            |
| /CS <sup>*2</sup>             | Chip select                                                         |
| /RAS, /CAS, /WE <sup>*2</sup> | Command input                                                       |
| CKE <sup>*2</sup>             | Clock enable                                                        |
| CK, /CK                       | Differential clock input                                            |
| DMU, DML                      | Write data mask                                                     |
| ODT <sup>*2</sup>             | ODT control                                                         |

| Pin name             | Function                            |
|----------------------|-------------------------------------|
| /RESET <sup>*2</sup> | Active low asynchronous reset       |
| VDD                  | Supply voltage for internal circuit |
| VSS                  | Ground for internal circuit         |
| VDDQ                 | Supply voltage for DQ circuit       |
| VSSQ                 | Ground for DQ circuit               |
| VREFDQ               | Reference voltage for DQ            |
| VREFCA               | Reference voltage for CA            |
| ZQ                   | Reference pin for ZQ calibration    |
| NC <sup>*1</sup>     | No connection                       |

Notes : 1. Not internally connected with die.

2. Input only pins (address, command, CKE,ODT and /RESET) do not supply termination.

CONTENTS

Specifications ..... 1

Features ..... 1

Revision History ..... 2

Ordering Information ..... 3

Part Number ..... 3

Pin Configurations ..... 4

1. Electrical Conditions ..... 7

    1.1 Absolute Maximum Ratings ..... 7

    1.2 Operating Temperature Condition ..... 7

    1.3 Recommended DC Operating Conditions ..... 8

    1.4 IDD and IDDQ Measurement Conditions ..... 9

2. Electrical Specifications ..... 22

    2.1 DC Characteristics ..... 22

    2.2 Pin Capacitance ..... 24

    2.3 Standard Speed Bins ..... 25

3. Package Drawing ..... 29

    3.1 78-ball FBGA ..... 29

    3.2 96-ball FBGA ..... 30

## 1. Electrical Conditions

- All voltages are referenced to VSS (GND)
- Execute power-up and Initialization sequence before proper device operation is achieved.

### 1.1 Absolute Maximum Ratings

Table 1: Absolute Maximum Ratings

| Parameter                       | Symbol | Rating                     | Unit | Notes |
|---------------------------------|--------|----------------------------|------|-------|
| Power supply voltage            | VDD    | −0.4 to +1.80              | V    | 1, 3  |
| Power supply voltage for output | VDDQ   | −0.4 to +1.80              | V    | 1, 3  |
| Input voltage                   | VIN    | −0.4 to +1.80              | V    | 1     |
| Output voltage                  | VOOUT  | −0.4 to +1.80              | V    | 1     |
| Reference voltage               | VREFCA | 0.49 to $0.51 \times VDD$  | V    | 3     |
| Reference voltage for DQ        | VREFDQ | 0.49 to $0.51 \times VDDQ$ | V    | 3     |
| Storage temperature             | Tstg   | −55 to +100                | °C   |       |
| Power dissipation               | PD     | 1.0                        | W    | 1     |
| Short circuit output current    | IOUT   | 50                         | mA   | 1     |

- Notes: 1. Stresses greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Storage temperature is the case surface temperature on the center/top side of the DRAM.
3. VDD and VDDQ must be within 300mV of each other at all times; and VREF must be no greater than  $0.6 \times VDDQ$ . When VDD and VDDQ are less than 500mV; VREF may be equal to or less than 300mV.

**Caution: Exposing the device to stress above those listed in Absolute Maximum Ratings could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.**

### 1.2 Operating Temperature Condition

Table 2: Operating Temperature Condition

| Parameter              | Rating      | Unit | Notes   |
|------------------------|-------------|------|---------|
| Commercial temperature | 0 to +95    | °C   | 1, 2, 3 |
| Industrial temperature | −40 to +95  | °C   | 1, 2, 3 |
| Automotive temperature | −40 to +105 | °C   | 1, 2, 3 |

- Notes: 1. Operating temperature is the case surface temperature on the center/top side of the DRAM.
2. The Normal Temperature Range specifies the temperatures where all DRAM specifications will be supported. During operation, the DRAM temperature must be maintained between 0°C to +85°C for commercial temperature, −40°C to +85°C for industrial/automotive temperature under all operating conditions.
3. Some applications require operation of the DRAM in the Extended Temperature Range between +85°C to +95°C for commercial/industrial operating temperature and +85°C to +105°C for automotive operating temperature. Full specifications are guaranteed in this range, but the following additional conditions apply:
- a) Refresh commands must be doubled in frequency, therefore reducing the refresh interval tREFI to 3.9μs. (This double refresh requirement may not apply for some devices.)
- b) If Self-refresh operation is required in the Extended Temperature Range, then it is mandatory to either use the Manual Self-Refresh mode with Extended Temperature Range capability (MR2 bit [A6, A7] = [0, 1]) or enable the optional Auto Self-Refresh mode (MR2 bit [A6, A7] = [1, 0]).

### 1.3 Recommended DC Operating Conditions

**Table 3-a: Recommended DC Operating Conditions, DDR3L Operation.**

| Parameter             | Symbol | min   | typ  | max  | Unit | Notes   |
|-----------------------|--------|-------|------|------|------|---------|
| Supply voltage        | VDD    | 1.283 | 1.35 | 1.45 | V    | 1, 2, 3 |
| Supply voltage for DQ | VDDQ   | 1.283 | 1.35 | 1.45 | V    | 1, 2, 3 |

- Notes: 1. Under all conditions VDDQ must be less than or equal to VDD.  
2. VDDQ tracks with VDD. AC parameters are measured with VDD and VDDQ tied together.  
3. Commercial Temperature 0°C to +95°C, Industrial Temperature -40°C to +95° and Automotive Temperature -40°C to +105°C.

**Table 3-b: Recommended DC Operating Conditions, DDR3 Operation.**

| Parameter             | Symbol | min   | typ | max   | Unit | Notes   |
|-----------------------|--------|-------|-----|-------|------|---------|
| Supply voltage        | VDD    | 1.425 | 1.5 | 1.575 | V    | 1, 2, 3 |
| Supply voltage for DQ | VDDQ   | 1.425 | 1.5 | 1.575 | V    | 1, 2, 3 |

- Notes: 1. Under all conditions VDDQ must be less than or equal to VDD.  
2. VDDQ tracks with VDD. AC parameters are measured with VDD and VDDQ tied together.  
3. Commercial Temperature 0°C to +95°C, Industrial Temperature -40°C to +95° and Automotive Temperature -40°C to +105°C.

## 1.4 IDD and IDDQ Measurement Conditions

In this chapter, IDD and IDDQ measurement conditions such as test load and patterns are defined.

The figure Measurement Setup and Test Load for IDD and IDDQ Measurements shows the setup and test load for IDD and IDDQ measurements.

- IDD currents (such as IDD0, IDD1, IDD2N, IDD2NT, IDD2P0, IDD2P1, IDD2Q, IDD3N, IDD3P, IDD4R, IDD4W, IDD5B, IDD6, IDD6ET and IDD7) are measured as time-averaged currents with all VDD balls of the DDR3 SDRAM under test tied together. Any IDDQ current is not included in IDD currents.
- IDDQ currents (such as IDDQ2NT and IDDQ4R) are measured as time-averaged currents with all VDDQ balls of the DDR3 SDRAM under test tied together. Any IDD current is not included in IDDQ currents.

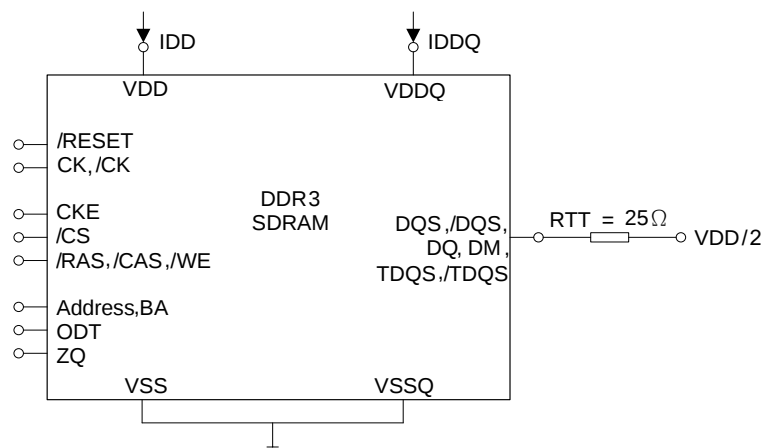
Note: IDDQ values cannot be directly used to calculate I/O power of the DDR3 SDRAM. They can be used to support correlation of simulated I/O power to actual I/O power as outlined in correlation from simulated channel I/O power to actual channel I/O power supported by IDDQ measurement.

For IDD and IDDQ measurements, the following definitions apply:

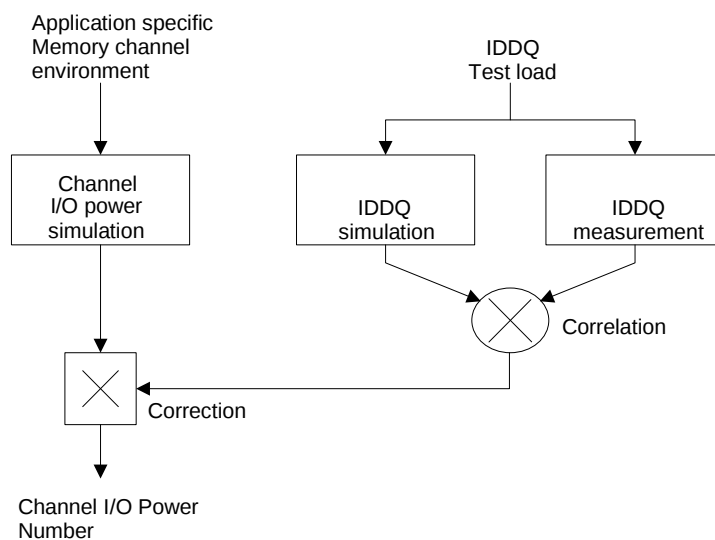
- L and 0:  $V_{IN} \leq V_{IL(AC)max}$
- H and 1:  $V_{IN} \geq V_{IH(AC)min}$
- MID-LEVEL: defined as inputs are  $V_{REF} = V_{DDQ} / 2$
- FLOATING: don't care or floating around  $V_{REF}$ .
- Timings used for IDD and IDDQ measurement-loop patterns are provided in Timings used for IDD and IDDQ Measurement-Loop Patterns table.
- Basic IDD and IDDQ measurement conditions are described in Basic IDD and IDDQ Measurement Conditions table.

Note: The IDD and IDDQ measurement-loop patterns need to be executed at least one time before actual IDD or IDDQ measurement is started.

- Detailed IDD and IDDQ measurement-loop patterns are described in IDD0 Measurement-Loop Pattern table through IDD7 Measurement-Loop Pattern table.
- IDD Measurements are done after properly initializing the DDR3 SDRAM. This includes but is not limited to setting.
  - RON = RZQ/7 (34Ω in MR1);
  - Qoff = 0B (Output Buffer enabled in MR1);
  - RTT\_Nom = RZQ/6 (40Ω in MR1);
  - RTT\_WR = RZQ/2 (120Ω in MR2);
  - TDQS Feature disabled in MR1
- Define D = {/CS, /RAS, /CAS, /WE} : = {H, L, L, L}
- Define /D = {/CS, /RAS, /CAS, /WE} : = {H, H, H, H}



**Figure 1: Measurement Setup and Test Load for IDD and IDDQ Measurements**



**Figure 2: Correlation from Simulated Channel I/O Power to Actual Channel I/O Power Supported by IDDQ Measurement**

#### 1.4.1 Timings Used for IDD and IDDQ Measurement-Loop Patterns

Table 4 : Timings Used for IDD and IDDQ Measurement-Loop Patterns

|           | DDR3L-1333 | DDR3L-1600 | DDR3L-1866 | DDR3L-2133 |      |
|-----------|------------|------------|------------|------------|------|
| Parameter | 9-9-9      | 11-11-11   | 13-13-13   | 14-14-14   | Unit |
| CL        | 9          | 11         | 13         | 14         | nCK  |
| tCK(min)  | 1.5        | 1.25       | 1.071      | 0.938      | ns   |
| nRCD(min) | 9          | 11         | 13         | 14         | nCK  |
| nRC(min)  | 33         | 39         | 45         | 50         | nCK  |
| nRAS(min) | 24         | 28         | 32         | 36         | nCK  |
| nRP(min)  | 9          | 11         | 13         | 14         | nCK  |
| nFAW      | 30         | 32         | 33         | 27         | nCK  |
| nRRD      | 5          | 6          | 6          | 6          | nCK  |
| nRFC      | 174        | 208        | 243        | 279        | nCK  |

### 1.4.2 Basic IDD and IDDQ Measurement Conditions

**Table 5: Basic IDD and IDDQ Measurement Conditions**

| Parameter                                        | Symbol  | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
|--------------------------------------------------|---------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Operating one bank active precharge current      | IDD0    | CKE: H; External clock: on; tCK, nRC, nRAS, CL: see <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS: H between ACT and PRE; Command, address, bank address inputs: partially toggling according to <a href="#">Table 6</a> ; Data I/O: MID-LEVEL; DM: stable at 0; Bank activity: cycling with one bank active at a time: 0,0,1,1,2,2,... (see <a href="#">Table 6</a> ); Output buffer and RTT: enabled in MR*2; ODT signal: stable at 0; Pattern details: see <a href="#">Table 6</a>                                                                                                            |
| Operating one bank active-read-precharge current | IDD1    | CKE: H; External clock: On; tCK, nRC, nRAS, nRCD, CL: see <a href="#">Table 4</a> ; BL: 8*1, *6; AL: 0; /CS: H between ACT, RD and PRE; Command, address, bank address inputs, data I/O: partially toggling according to <a href="#">Table 7</a> ; DM: stable at 0; Bank activity: cycling with one bank active at a time: 0,0,1,1,2,2,... (see <a href="#">Table 7</a> ); Output buffer and RTT: enabled in MR*2; ODT Signal: stable at 0; Pattern details: see <a href="#">Table 7</a>                                                                                                         |
| Precharge standby current                        | IDD2N   | CKE: H; External clock: on; tCK, CL: see <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS: stable at 1; Command, address, bank address Inputs: partially toggling according to <a href="#">Table 8</a> ; data I/O: MID-LEVEL; DM: stable at 0; bank activity: all banks closed; output buffer and RTT: enabled in mode registers*2; ODT signal: stable at 0; pattern details: see <a href="#">Table 8</a>                                                                                                                                                                                           |
| Precharge standby ODT current                    | IDD2NT  | CKE: H; External clock: on; tCK, CL: see <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS: stable at 1; Command, address, bank address Inputs: partially toggling according to <a href="#">Table 9</a> ; data I/O: MID-LEVEL; DM: stable at 0; bank activity: all banks closed; output buffer and RTT: enabled in MR*2; ODT signal: toggling according to <a href="#">Table 9</a> ; pattern details: see <a href="#">Table 9</a>                                                                                                                                                                    |
| Precharge standby ODT IDDQ current               | IDDQ2NT | Same definition like for IDD2NT, however measuring IDDQ current instead of IDD current                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| Precharge power-down current slow exit           | IDD2P0  | CKE: L; External clock: on; tCK, CL: see <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS: stable at 1; Command, address, bank address inputs: stable at 0; data I/O: MID-LEVEL; DM: stable at 0; bank activity: all banks closed; output buffer and RTT: EMR*2; ODT signal: stable at 0; precharge power down mode: slow exit*3                                                                                                                                                                                                                                                                    |
| Precharge power-down current fast exit           | IDD2P1  | CKE: L; External clock: on; tCK, CL: see <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS: stable at 1; Command, address, bank address Inputs: stable at 0; data I/O: MID-LEVEL; DM: stable at 0; bank activity: all banks closed; output buffer and RTT: enabled in MR*2; ODT signal: stable at 0; precharge power down mode: fast exit*3                                                                                                                                                                                                                                                          |
| Precharge quiet standby current                  | IDD2Q   | CKE: H; External clock: On; tCK, CL: see <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS: stable at 1; Command, address, bank address Inputs: stable at 0; data I/O: MID-LEVEL; DM: stable at 0; bank activity: all banks closed; output buffer and RTT: enabled in MR*2; ODT signal: stable at 0                                                                                                                                                                                                                                                                                                  |
| Active standby current                           | IDD3N   | CKE: H; External clock: on; tCK, CL: see <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS: stable at 1; Command, address, bank address Inputs: partially toggling according to <a href="#">Table 8</a> ; data I/O: MID-LEVEL; DM: stable at 0; bank activity: all banks open; output buffer and RTT: enabled in MR*2; ODT signal: stable at 0; pattern details: see <a href="#">Table 8</a>                                                                                                                                                                                                         |
| Active power-down current                        | IDD3P   | CKE: L; External clock: on; tCK, CL: see <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS: stable at 1; Command, address, bank address inputs: stable at 0; data I/O: MID-LEVEL; DM: stable at 0; bank activity: all banks open; output buffer and RTT: enabled in MR*2; ODT signal: stable at 0                                                                                                                                                                                                                                                                                                    |
| Operating burst read current                     | IDD4R   | CKE: H; External clock: on; tCK, CL: see <a href="#">Table 4</a> ; BL: 8*1, *6; AL: 0; /CS: H between RD; Command, address, bank address Inputs: partially toggling according to <a href="#">Table 11</a> ; data I/O: seamless read data burst with different data between one burst and the next one according to <a href="#">Table 11</a> ; DM: stable at 0; bank activity: all banks open, RD commands cycling through banks: 0,0,1,1,2,2,... (see <a href="#">Table 11</a> ); Output buffer and RTT: enabled in MR*2; ODT signal: stable at 0; pattern details: see <a href="#">Table 11</a> |

**Table 5: Basic IDD and IDDQ Measurement Conditions (cont'd)**

| Parameter                                        | Symbol | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
|--------------------------------------------------|--------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Operating burst write current                    | IDD4W  | CKE: H; External clock: on; tCK, CL: see <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS: H between WR; command, address, bank address inputs: partially toggling according to <a href="#">Table 12</a> ; data I/O: seamless write data burst with different data between one burst and the next one according to IDD4W Measurement-Loop Pattern table; DM: stable at 0; bank activity: all banks open, WR commands cycling through banks: 0,0,1,1,2,2,... (see <a href="#">Table 12</a> ); Output buffer and RTT: enabled in MR*2; ODT signal: stable at H; pattern details: see <a href="#">Table 12</a>                                         |
| Burst refresh current                            | IDD5B  | CKE: H; External clock: on; tCK, CL, nRFC: see <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS: H between REF; Command, address, bank address Inputs: partially toggling according to <a href="#">Table 13</a> ; data I/O: MID-LEVEL; DM: stable at 0; bank activity: REF command every nRFC ( <a href="#">Table 12</a> ); output buffer and RTT: enabled in MR*2; ODT signal: stable at 0; pattern details: see <a href="#">Table 13</a>                                                                                                                                                                                                          |
| Self-refresh current: normal temperature range   | IDD6   | Commercial temperature : 0 to 85°C and Industrial temperature -40 to 85°C; ASR: disabled*4; SRT: Normal*5; CKE: L; External clock: off; CK and /CK: L; CL: see <a href="#">Table 4</a> ; BL: 8*1;AL: 0; /CS, command, address, bank address, data I/O: MID-LEVEL; DM: stable at 0; bank activity: Self-refresh operation; output buffer and RTT: enabled in MR*2; ODT signal: MID-LEVEL                                                                                                                                                                                                                                                          |
| Self-refresh current: extended temperature range | IDD6ET | Commercial temperature : 0 to 95°C and Industrial temperature -40 to 95°C; ASR: Disabled*4; SRT: Extended*5; CKE: L; External clock: off; CK and /CK: L; CL: <a href="#">Table 4</a> ; BL: 8*1; AL: 0; /CS, command, address, bank address, data I/O: MID-LEVEL; DM: stable at 0; bank activity: Extended temperature self-refresh operation; output buffer and RTT: enabled in MR*2; ODT signal: MID-LEVEL                                                                                                                                                                                                                                      |
| Operating bank interleave read current           | IDD7   | CKE: H; External clock: on; tCK, nRC, nRAS, nRCD, nRRD, nFAW, CL: see <a href="#">Table 4</a> ; BL: 8*1, *6; AL: CL-1; /CS: H between ACT and RDA; Command, address, bank address Inputs: partially toggling according to <a href="#">Table 15</a> ; data I/O: read data bursts with different data between one burst and the next one according to <a href="#">Table 15</a> ; DM: stable at 0; bank activity: two times interleaved cycling through banks (0, 1, ...7) with different addressing, see <a href="#">Table 15</a> ; output buffer and RTT: enabled in MR*2; ODT signal: stable at 0; pattern details: see <a href="#">Table 15</a> |
| RESET low current                                | IDD8   | /RESET: low; External clock: off; CK and /CK: low; CKE: FLOATING; /CS, command, address, bank address, Data IO: FLOATING; ODT signal: FLOATING<br>RESET low current reading is valid once power is stable and /RESET has been low for at least 1ms.                                                                                                                                                                                                                                                                                                                                                                                              |

- Notes: 1. Burst Length: BL8 fixed by MRS: MR0 bits [1,0] = [0,0].  
2. MR: Mode Register  
Output buffer enable: set MR1 bit A12 = 1 and MR1 bits [5, 1] = [0,1];  
RTT\_Nom enable: set MR1 bits [9, 6, 2] = [0, 1, 1]; RTT\_WR enable: set MR2 bits [10, 9] = [1,0].  
3. Precharge power down mode: set MR0 bit A12= 0 for Slow Exit or MR0 bit A12 = 1 for fast exit.  
4. Auto self-refresh (ASR): set MR2 bit A6 = 0 to disable or 1 to enable feature.  
5. Self-refresh temperature range (SRT): set MR0 bit A7= 0 for normal or 1 for extended temperature range.  
6. Read burst type: nibble sequential, set MR0 bit A3 = 0

Table 6: IDD0 Measurement-Loop Pattern

| CK,<br>/CK        | CKE | Sub<br>-Loop | Cycle<br>number   | Com-<br>mand                                                               | /CS                                  | /RAS | /CAS | /WE | ODT | BA* <sup>3</sup> | A11<br>-Am | A10 | A7<br>-A9 | A3<br>-A6 | A0<br>-A2 | Data* <sup>2</sup> |
|-------------------|-----|--------------|-------------------|----------------------------------------------------------------------------|--------------------------------------|------|------|-----|-----|------------------|------------|-----|-----------|-----------|-----------|--------------------|
| Toggling Static H | 0   | 0            | 0                 | ACT                                                                        | 0                                    | 0    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | 0         | 0         |                    |
|                   |     |              | 1, 2              | D, D                                                                       | 1                                    | 0    | 0    | 0   | 0   | 0                | 0          | 0   | 0         | 0         | 0         |                    |
|                   |     |              | 3, 4              | /D, /D                                                                     | 1                                    | 1    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | 0         | 0         |                    |
|                   |     |              | ...               | Repeat pattern 1...4 until nRAS - 1, truncate if necessary                 |                                      |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | nRAS              | PRE                                                                        | 0                                    | 0    | 1    | 0   | 0   | 0                | 0          | 0   | 0         | 0         | 0         |                    |
|                   |     |              | ...               | Repeat pattern 1...4 until nRC - 1, truncate if necessary                  |                                      |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 1 x nRC<br>+ 0    | ACT                                                                        | 0                                    | 0    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | F         | 0         |                    |
|                   |     |              | 1 x nRC<br>+ 1, 2 | D, D                                                                       | 1                                    | 0    | 0    | 0   | 0   | 0                | 0          | 0   | 0         | F         | 0         |                    |
|                   |     |              | 1 x nRC<br>+ 3, 4 | /D, /D                                                                     | 1                                    | 1    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | F         | 0         |                    |
|                   |     |              | ...               | Repeat pattern nRC + 1,...,4 until 1*nRC + nRAS - 1, truncate if necessary |                                      |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 1 x nRC<br>+ nRAS | PRE                                                                        | 0                                    | 0    | 1    | 0   | 0   | 0                | 0          | 0   | 0         | F         | 0         |                    |
|                   |     |              | ...               | Repeat nRC + 1,...,4 until 2 x nRC - 1, truncate if necessary              |                                      |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 1                 | 2 x nRC                                                                    | Repeat Sub-Loop 0, use BA= 1 instead |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 2                 | 4 x nRC                                                                    | Repeat Sub-Loop 0, use BA= 2 instead |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 3                 | 6 x nRC                                                                    | Repeat Sub-Loop 0, use BA= 3 instead |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 4                 | 8 x nRC                                                                    | Repeat Sub-Loop 0, use BA= 4 instead |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 5                 | 10 x nRC                                                                   | Repeat Sub-Loop 0, use BA= 5 instead |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 6                 | 12 x nRC                                                                   | Repeat Sub-Loop 0, use BA= 6 instead |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 7                 | 14 x nRC                                                                   | Repeat Sub-Loop 0, use BA= 7 instead |      |      |     |     |                  |            |     |           |           |           |                    |

- Notes: 1. DM must be driven low all the time. DQS, /DQS are FLOATING.  
2. DQ signals are FLOATING.  
3. BA: BA0 to BA2.  
4. Am: m means Most Significant Bit (MSB) of Row address.

**Table 7: IDD1 Measurement-Loop Pattern**

| CK,<br>/CK        | CKE | Sub<br>-Loop | Cycle<br>number | Com-<br>mand                                                              |     |      |      |     |     | A11              |     | A7  |     | A3  | A0  | Data* <sup>2</sup> |
|-------------------|-----|--------------|-----------------|---------------------------------------------------------------------------|-----|------|------|-----|-----|------------------|-----|-----|-----|-----|-----|--------------------|
|                   |     |              |                 |                                                                           | /CS | /RAS | /CAS | /WE | ODT | BA* <sup>3</sup> | -Am | A10 | -A9 | -A6 | -A2 |                    |
| Toggling Static H |     | 0            | 0               | ACT                                                                       | 0   | 0    | 1    | 1   | 0   | 0                | 0   | 0   | 0   | 0   | 0   | —                  |
|                   |     |              | 1, 2            | D, D                                                                      | 1   | 0    | 0    | 0   | 0   | 0                | 0   | 0   | 0   | 0   | 0   | —                  |
|                   |     |              | 3, 4            | /D, /D                                                                    | 1   | 1    | 1    | 1   | 0   | 0                | 0   | 0   | 0   | 0   | 0   | —                  |
|                   |     |              | ...             | Repeat pattern 1...4 until nRCD - 1, truncate if necessary                |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     |              | nRCD            | RD                                                                        | 0   | 1    | 0    | 1   | 0   | 0                | 0   | 0   | 0   | 0   | 0   | 00000000           |
|                   |     |              | ...             | Repeat pattern 1...4 until nRAS - 1, truncate if necessary                |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     |              | nRAS            | PRE                                                                       | 0   | 0    | 1    | 0   | 0   | 0                | 0   | 0   | 0   | 0   | 0   | —                  |
|                   |     |              | ...             | Repeat pattern 1...4 until nRC - 1, truncate if necessary                 |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     |              | 1 x nRC + 0     | ACT                                                                       | 0   | 0    | 1    | 1   | 0   | 0                | 0   | 0   | 0   | F   | 0   | —                  |
|                   |     |              | 1 x nRC + 1, 2  | D, D                                                                      | 1   | 0    | 0    | 0   | 0   | 0                | 0   | 0   | 0   | F   | 0   | —                  |
|                   |     |              | 1 x nRC + 3, 4  | /D, /D                                                                    | 1   | 1    | 1    | 1   | 0   | 0                | 0   | 0   | 0   | F   | 0   | —                  |
|                   |     |              | ...             | Repeat pattern nRC + 1,..., 4 until nRC + nRCD - 1, truncate if necessary |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     |              | 1 x nRC + nRCD  | RD                                                                        | 0   | 1    | 0    | 1   | 0   | 0                | 0   | 0   | 0   | F   | 0   | 00110011           |
|                   |     |              | ...             | Repeat pattern nRC + 1,..., 4 until nRC + nRAS - 1, truncate if necessary |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     |              | 1 x nRC + nRAS  | PRE                                                                       | 0   | 0    | 1    | 0   | 0   | 0                | 0   | 0   | 0   | F   | 0   | —                  |
|                   |     |              | ...             | Repeat pattern nRC + 1,..., 4 until 2 x nRC - 1, truncate if necessary    |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     | 1            | 2 x nRC         | Repeat Sub-Loop 0, use BA= 1 instead                                      |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     | 2            | 4 x nRC         | Repeat Sub-Loop 0, use BA= 2 instead                                      |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     | 3            | 6 x nRC         | Repeat Sub-Loop 0, use BA= 3 instead                                      |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     | 4            | 8 x nRC         | Repeat Sub-Loop 0, use BA= 4 instead                                      |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     | 5            | 10 x nRC        | Repeat Sub-Loop 0, use BA= 5 instead                                      |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     | 6            | 12 x nRC        | Repeat Sub-Loop 0, use BA= 6 instead                                      |     |      |      |     |     |                  |     |     |     |     |     |                    |
|                   |     | 7            | 14 x nRC        | Repeat Sub-Loop 0, use BA= 7 instead                                      |     |      |      |     |     |                  |     |     |     |     |     |                    |

- Notes: 1. DM must be driven low all the time. DQS, /DQS are used according to read commands, otherwise FLOATING.  
2. Burst sequence driven on each DQ signal by read command. Outside burst operation, DQ signals are FLOATING.  
3. BA: BA0 to BA2.  
4. Am: m means Most Significant Bit (MSB) of Row address.

**Table 8: IDD2N and IDD3N Measurement-Loop Pattern**

| CK,<br>/CK        | CKE | Sub<br>-Loop | Cycle<br>number | Com-<br>mand                         | /CS | /RAS | /CAS | /WE | ODT | BA* <sup>3</sup> | A11<br>-Am | A10 | A7<br>-A9 | A3<br>-A6 | A0<br>-A2 | Data* <sup>2</sup> |
|-------------------|-----|--------------|-----------------|--------------------------------------|-----|------|------|-----|-----|------------------|------------|-----|-----------|-----------|-----------|--------------------|
| Toggling Static H |     | 0            | 0               | D                                    | 1   | 0    | 0    | 0   | 0   | 0                | 0          | 0   | 0         | 0         | 0         | 0                  |
|                   |     |              | 1               | D                                    | 1   | 0    | 0    | 0   | 0   | 0                | 0          | 0   | 0         | 0         | 0         | 0                  |
|                   |     |              | 2               | /D                                   | 1   | 1    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | F         | 0         | 0                  |
|                   |     |              | 3               | /D                                   | 1   | 1    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | F         | 0         | 0                  |
|                   |     | 1            | 4 to 7          | Repeat Sub-Loop 0, use BA= 1 instead |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 2            | 8 to 11         | Repeat Sub-Loop 0, use BA= 2 instead |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 3            | 12 to 15        | Repeat Sub-Loop 0, use BA= 3 instead |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 4            | 16 to 19        | Repeat Sub-Loop 0, use BA= 4 instead |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 5            | 20 to 23        | Repeat Sub-Loop 0, use BA= 5 instead |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 6            | 24 to 27        | Repeat Sub-Loop 0, use BA= 6 instead |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 7            | 28 to 31        | Repeat Sub-Loop 0, use BA= 7 instead |     |      |      |     |     |                  |            |     |           |           |           |                    |

- Notes: 1. DM must be driven low all the time. DQS, /DQS are FLOATING.  
2. DQ signals are FLOATING.  
3. BA: BA0 to BA2.  
4. Am: m means Most Significant Bit (MSB) of Row address.

**Table 9: IDD2NT and IDDQ2NT Measurement-Loop Pattern**

| CK,<br>/CK        | CKE | Sub<br>-Loop | Cycle<br>number | Com-<br>mand                             | /CS | /RAS | /CAS | /WE | ODT | BA* <sup>3</sup> | A11<br>-Am | A10 | A7<br>-A9 | A3<br>-A6 | A0<br>-A2 | Data* <sup>2</sup> |
|-------------------|-----|--------------|-----------------|------------------------------------------|-----|------|------|-----|-----|------------------|------------|-----|-----------|-----------|-----------|--------------------|
| Toggling Static H |     | 0            | 0               | D                                        | 1   | 0    | 0    | 0   | 0   | 0                | 0          | 0   | 0         | 0         | 0         | 0                  |
|                   |     |              | 1               | D                                        | 1   | 0    | 0    | 0   | 0   | 0                | 0          | 0   | 0         | 0         | 0         | 0                  |
|                   |     |              | 2               | /D                                       | 1   | 1    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | F         | 0         | 0                  |
|                   |     |              | 3               | /D                                       | 1   | 1    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | F         | 0         | 0                  |
|                   |     | 1            | 4 to 7          | Repeat Sub-Loop 0, but ODT = 0 and BA= 1 |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 2            | 8 to 11         | Repeat Sub-Loop 0, but ODT = 1 and BA= 2 |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 3            | 12 to 15        | Repeat Sub-Loop 0, but ODT = 1 and BA= 3 |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 4            | 16 to 19        | Repeat Sub-Loop 0, but ODT = 0 and BA= 4 |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 5            | 20 to 23        | Repeat Sub-Loop 0, but ODT = 0 and BA= 5 |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 6            | 24 to 27        | Repeat Sub-Loop 0, but ODT = 1 and BA= 6 |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 7            | 28 to 31        | Repeat Sub-Loop 0, but ODT = 1 and BA= 7 |     |      |      |     |     |                  |            |     |           |           |           |                    |

- Notes: 1. DM must be driven low all the time. DQS, /DQS are FLOATING.  
2. DQ signals are FLOATING.  
3. BA: BA0 to BA2.  
4. Am: m means Most Significant Bit (MSB) of Row address.

**Table 10: IDD2P0, IDD2P1, IDD2Q and IDD3P Measurement-Loop Pattern**

| External Clock | Name                                            | CK           | CKE | RC  | RAS | RCD | RRD | CL  | AL  | CSB | Comm and | A0-Am | BA | DM | ODT        | DQ, DQS | Burst length | Active banks | Idle banks | Data     |
|----------------|-------------------------------------------------|--------------|-----|-----|-----|-----|-----|-----|-----|-----|----------|-------|----|----|------------|---------|--------------|--------------|------------|----------|
| Toggling       | IDD2P0 Precharge Power-Down Current (Slow Exit) | CK (MIN) IDD | 0   | N/A | N/A | N/A | N/A | N/A | N/A | 1   | 0        | 0     | 0  | 0  | Acted, off | Acted   | 8            | None         | All        | Midlevel |
|                | IDD2P1 Precharge Power-Down Current (Fast Exit) | CK (MIN) IDD | 0   | N/A | N/A | N/A | N/A | N/A | N/A | 1   | 0        | 0     | 0  | 0  | Acted, off | Acted   | 8            | None         | All        | Midlevel |
|                | IDD2Q Precharge Quiet Standby Current           | CK (MIN) IDD | 1   | N/A | N/A | N/A | N/A | N/A | N/A | 1   | 0        | 0     | 0  | 0  | Acted, off | Acted   | 8            | None         | All        | Midlevel |
|                | IDD3P Active Power-Down Current                 | CK (MIN) IDD | 0   | N/A | N/A | N/A | N/A | N/A | N/A | 1   | 0        | 0     | 0  | 0  | Acted, off | Acted   | 8            | All          | None       | Midlevel |

- Notes: 1. MR0[12] defines DLL on/off behavior during precharge power-down only; DLL on (fast exit, MR0[12] = 1) and DLL off (slow exit, MR0[12] = 0).
2. "Acted, off" means the MR bits are enabled, but the signal is LOW.

Table 11: IDD4R and Measurement-Loop Pattern

| CK,<br>/CK        | CKE | Sub<br>-Loop | Cycle<br>number | Com-<br>mand | /CS                          | /RAS | /CAS | /WE | ODT | BA* <sup>3</sup> | A11<br>-Am | A10 | A7<br>-A9 | A3<br>-A6 | A0<br>-A2 | Data* <sup>2</sup> |
|-------------------|-----|--------------|-----------------|--------------|------------------------------|------|------|-----|-----|------------------|------------|-----|-----------|-----------|-----------|--------------------|
| Toggling Static H |     | 0            | 0               | RD           | 0                            | 1    | 0    | 1   | 0   | 0                | 0          | 0   | 0         | 0         | 0         | 00000000           |
|                   |     |              | 1               | D            | 1                            | 0    | 0    | 0   | 0   | 0                | 0          | 0   | 0         | 0         | 0         | —                  |
|                   |     |              | 2,3             | /D, /D       | 1                            | 1    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | 0         | 0         | —                  |
|                   |     |              | 4               | RD           | 0                            | 1    | 0    | 1   | 0   | 0                | 0          | 0   | 0         | F         | 0         | 00110011           |
|                   |     |              | 5               | D            | 1                            | 0    | 0    | 0   | 0   | 0                | 0          | 0   | 0         | F         | 0         | —                  |
|                   |     |              | 6,7             | /D, /D       | 1                            | 1    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | F         | 0         | —                  |
|                   |     |              | 1               | 8 to 15      | Repeat Sub-Loop 0, but BA= 1 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 2               | 16 to 23     | Repeat Sub-Loop 0, but BA= 2 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 3               | 24 to 31     | Repeat Sub-Loop 0, but BA= 3 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 4               | 32 to 39     | Repeat Sub-Loop 0, but BA= 4 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 5               | 40 to 47     | Repeat Sub-Loop 0, but BA= 5 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 6               | 48 to 55     | Repeat Sub-Loop 0, but BA= 6 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 7               | 56 to 63     | Repeat Sub-Loop 0, but BA= 7 |      |      |     |     |                  |            |     |           |           |           |                    |

- Notes: 1. DM must be driven low all the time. DQS, /DQS are used according to read commands, otherwise FLOATING.  
2. Burst sequence driven on each DQ signal by read command. Outside burst operation, DQ signals are FLOATING.  
3. BA: BA0 to BA2.  
4. Am: m means Most Significant Bit (MSB) of Row address.

**Table 12: IDD4W Measurement-Loop Pattern**

| CK,<br>/CK        | CKE | Sub<br>-Loop | Cycle<br>number | Com-<br>mand | /CS                          | /RAS | /CAS | /WE | ODT | BA* <sup>3</sup> | A11<br>-Am | A10 | A7<br>-A9 | A3<br>-A6 | A0<br>-A2 | Data* <sup>2</sup> |
|-------------------|-----|--------------|-----------------|--------------|------------------------------|------|------|-----|-----|------------------|------------|-----|-----------|-----------|-----------|--------------------|
| Toggling Static H |     | 0            | 0               | WR           | 0                            | 1    | 0    | 0   | 1   | 0                | 0          | 0   | 0         | 0         | 0         | 00000000           |
|                   |     |              | 1               | D            | 1                            | 0    | 0    | 0   | 1   | 0                | 0          | 0   | 0         | 0         | 0         | —                  |
|                   |     |              | 23              | /D, /D       | 1                            | 1    | 1    | 1   | 1   | 0                | 0          | 0   | 0         | 0         | 0         | —                  |
|                   |     |              | 4               | RD           | 0                            | 1    | 0    | 0   | 1   | 0                | 0          | 0   | 0         | F         | 0         | 00110011           |
|                   |     |              | 5               | D            | 1                            | 0    | 0    | 0   | 1   | 0                | 0          | 0   | 0         | F         | 0         | —                  |
|                   |     |              | 6,7             | /D, /D       | 1                            | 1    | 1    | 1   | 1   | 0                | 0          | 0   | 0         | F         | 0         | —                  |
|                   |     |              | 1               | 8 to 15      | Repeat Sub-Loop 0, but BA= 1 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 2               | 16 to 23     | Repeat Sub-Loop 0, but BA= 2 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 3               | 24 to 31     | Repeat Sub-Loop 0, but BA= 3 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 4               | 32 to 39     | Repeat Sub-Loop 0, but BA= 4 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 5               | 40 to 47     | Repeat Sub-Loop 0, but BA= 5 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 6               | 48 to 55     | Repeat Sub-Loop 0, but BA= 6 |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 7               | 56 to 63     | Repeat Sub-Loop 0, but BA= 7 |      |      |     |     |                  |            |     |           |           |           |                    |

- Notes: 1. DM must be driven low all the time. DQS, /DQS are used according to read commands, otherwise FLOATING.  
2. Burst sequence driven on each DQ signal by read command. Outside burst operation, DQ signals are FLOATING.  
3. BA: BA0 to BA2.  
4. Am: m means Most Significant Bit (MSB) of Row address.

**Table 13: IDD5B Measurement-Loop Pattern**

| CK,<br>/CK        | CKE | Sub<br>-Loop | Cycle<br>number | Com-<br>mand                                              | /CS | /RAS | /CAS | /WE | ODT | BA* <sup>3</sup> | A11<br>-Am | A10 | A7<br>-A9 | A3<br>-A6 | A0<br>-A2 | Data* <sup>2</sup> |
|-------------------|-----|--------------|-----------------|-----------------------------------------------------------|-----|------|------|-----|-----|------------------|------------|-----|-----------|-----------|-----------|--------------------|
| Toggling Static H |     | 0            | 0               | REF                                                       | 0   | 0    | 0    | 1   | 0   | 0                | 0          | 0   | 0         | 0         | 0         | —                  |
|                   |     |              | 1, 2            | D                                                         | 1   | 0    | 0    | 0   | 0   | 0                | 0          | 0   | 0         | 0         | 0         | —                  |
|                   |     |              | 3,4             | /D, /D                                                    | 1   | 1    | 1    | 1   | 0   | 0                | 0          | 0   | 0         | F         | 0         | —                  |
|                   |     |              | 5 to 8          | Repeat cycles 1...4, but BA= 1                            |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 1            | 9 to 12         | Repeat cycles 1...4, but BA= 2                            |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 13 to 16        | Repeat cycles 1...4, but BA= 3                            |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 17 to 20        | Repeat cycles 1...4, but BA= 4                            |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 21 to 24        | Repeat cycles 1...4, but BA= 5                            |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 25 to 28        | Repeat cycles 1...4, but BA= 6                            |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     |              | 29 to 32        | Repeat cycles 1...4, but BA= 7                            |     |      |      |     |     |                  |            |     |           |           |           |                    |
|                   |     | 2            | 33 to nRFC - 1  | Repeat Sub-Loop 1, until nRFC - 1. Truncate, if necessary |     |      |      |     |     |                  |            |     |           |           |           |                    |

- Notes: 1. DM must be driven low all the time. DQS, /DQS are FLOATING.  
2. DQ signals are FLOATING.  
3. BA: BA0 to BA2.  
4. Am: m means Most Significant Bit (MSB) of Row address

Table 14: IDD6, IDD6ET and IDD8 Measurement-Loop Pattern

| External Clock        | Name                                                                                                                                                  | CK  | CKE      | RC  | RAS | RCD | RRD | CL       | AL | /CS | Comm and | A0-Am              | BA | SRT | ASR | ODT             | DQ, DQS  | Burst length | Active banks | Idle banks | Data     |
|-----------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------|-----|----------|-----|-----|-----|-----|----------|----|-----|----------|--------------------|----|-----|-----|-----------------|----------|--------------|--------------|------------|----------|
| Off, CK and /CK = Low | IDD6: Self Refresh Current Normal Temperature Range 0°C to +85°C                                                                                      | N/A | 0        | N/A |     |     |     | Midlevel |    |     |          | Disabled (normal)  |    |     |     | Acted, Midlevel | Acted    | N/A          | None         | All        | Midlevel |
|                       | IDD6: Self Refresh Current Extended Temperature Range Commercial-Temp: 0°C to +95°C, Industrial-Temp: -40°C to +95°C Automotive-Temp: -40°C to +105°C | N/A | 0        | N/A |     |     |     | Midlevel |    |     |          | Enabled (extended) |    |     |     | Acted, Midlevel | Acted    | N/A          | None         | All        | Midlevel |
| Midlevel              | IDD8: Reset                                                                                                                                           | N/A | Midlevel | N/A |     |     |     | Midlevel |    |     |          | N/A                |    |     |     | Midlevel        | Midlevel | N/A          | None         | All        | Midlevel |

- Notes: 1. "Acted, midlevel" means the MR command is enabled, but the signal is midlevel.
2. During a cold boot RESET (initialization), current reading is valid after power is stable and RESET has been LOW for 1ms;  
During a warm boot RESET (while operating), current reading is valid after RESET has been LOW for 200ns + tRFC.

**Table 15: IDD7 Measurement-Loop Pattern**

| CK,<br>/CK        | CKE | Sub<br>-Loop | Cycle<br>number                                                    | Com-<br>mand                              | /CS | /RAS | /CAS | /WE | ODT | BA*3 | A11<br>-Am | A10 | A7<br>-A9 | A3<br>-A6 | A0<br>-A2 | Data*2   |
|-------------------|-----|--------------|--------------------------------------------------------------------|-------------------------------------------|-----|------|------|-----|-----|------|------------|-----|-----------|-----------|-----------|----------|
| Toggling Static H |     | 0            | 0                                                                  | ACT                                       | 0   | 0    | 1    | 1   | 0   | 0    | 0          | 0   | 0         | 0         | 0         | —        |
|                   |     |              | 1                                                                  | RDA                                       | 0   | 1    | 0    | 1   | 0   | 0    | 0          | 1   | 0         | 0         | 0         | 00000000 |
|                   |     |              | 2                                                                  | D                                         | 1   | 0    | 0    | 0   | 0   | 0    | 0          | 0   | 0         | 0         | 0         | —        |
|                   |     |              | ...                                                                | Repeat above D Command until nRRD – 1     |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 1            | nRRD                                                               | ACT                                       | 0   | 0    | 1    | 1   | 0   | 1    | 0          | 0   | 0         | F         | 0         | —        |
|                   |     |              | nRRD + 1                                                           | RDA                                       | 0   | 1    | 0    | 1   | 0   | 1    | 0          | 1   | 0         | F         | 0         | 00110011 |
|                   |     |              | nRRD + 2                                                           | D                                         | 1   | 0    | 0    | 0   | 0   | 1    | 0          | 0   | 0         | F         | 0         | —        |
|                   |     |              | ...                                                                | Repeat above D Command until 2 x nRRD – 1 |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 2            | 2 x RRD                                                            | Repeat Sub-Loop 0, but BA= 2              |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 3            | 3 x RRD                                                            | Repeat Sub-Loop 1, but BA= 3              |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 4            | 4 x nRRD                                                           | D                                         | 1   | 0    | 0    | 0   | 0   | 3    | 0          | 0   | 0         | F         | 0         | —        |
|                   |     |              | Assert and repeat above D Command until nFAW – 1, if necessary     |                                           |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 5            | nFAW                                                               | Repeat Sub-Loop 0, but BA= 4              |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 6            | nFAW + nRRD                                                        | Repeat Sub-Loop 1, but BA= 5              |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 7            | nFAW + 2 x nRRD                                                    | Repeat Sub-Loop 0, but BA= 6              |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 8            | nFAW + 3 x nRRD                                                    | Repeat Sub-Loop 1, but BA= 7              |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 9            | nFAW + 4 x nRRD                                                    | D                                         | 1   | 0    | 0    | 0   | 0   | 7    | 0          | 0   | 0         | F         | 0         | —        |
|                   |     |              | Assert and repeat above D Command until 2 x nFAW – 1, if necessary |                                           |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 10           | 2 x nFAW + 0                                                       | ACT                                       | 0   | 0    | 1    | 1   | 0   | 0    | 0          | 0   | 0         | F         | 0         | —        |
|                   |     |              | 2 x nFAW + 1                                                       | RDA                                       | 0   | 1    | 0    | 1   | 0   | 0    | 0          | 1   | 0         | F         | 0         | 00110011 |
|                   |     |              | 2 x nFAW + 2                                                       | D                                         | 1   | 0    | 0    | 0   | 0   | 0    | 0          | 0   | 0         | F         | 0         | —        |
|                   |     |              | Repeat above D Command until 2 x nFAW + nRRD – 1                   |                                           |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 11           | 2 x nFAW + nRRD                                                    | ACT                                       | 0   | 0    | 1    | 1   | 0   | 1    | 0          | 0   | 0         | 0         | 0         | —        |
|                   |     |              | 2 x nFAW + nRRD + 1                                                | RDA                                       | 0   | 1    | 0    | 1   | 0   | 1    | 0          | 1   | 0         | 0         | 0         | 00000000 |
|                   |     |              | 2 x nFAW + nRRD + 2                                                | D                                         | 1   | 0    | 0    | 0   | 0   | 1    | 0          | 0   | 0         | 0         | 0         | —        |
|                   |     |              | Repeat above D Command until 2 x nFAW + 2 x nRRD – 1               |                                           |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 12           | 2 x nFAW + 2 x nRRD                                                | Repeat Sub-Loop 10, but BA= 2             |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 13           | 2 x nFAW + 3 x nRRD                                                | Repeat Sub-Loop 11, but BA= 3             |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 14           | 2 x nFAW + 4 x nRRD                                                | D                                         | 1   | 0    | 0    | 0   | 0   | 3    | 0          | 0   | 0         | 0         | 0         | —        |
|                   |     |              | Assert and repeat above D Command until 3 x nFAW – 1, if necessary |                                           |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 15           | 3 x nFAW                                                           | Repeat Sub-Loop 10, but BA= 4             |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 16           | 3 x nFAW + nRRD                                                    | Repeat Sub-Loop 11, but BA= 5             |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 17           | 3 x nFAW + 2 + nRRD                                                | Repeat Sub-Loop 10, but BA= 6             |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 18           | 3 x nFAW + 3 + nRRD                                                | Repeat Sub-Loop 11, but BA= 7             |     |      |      |     |     |      |            |     |           |           |           |          |
|                   |     | 19           | 3 x nFAW + 4 + nRRD                                                | D                                         | 1   | 0    | 0    | 0   | 0   | 7    | 0          | 0   | 0         | 0         | 0         | —        |
|                   |     |              | Assert and repeat above D Command until 4 x nFAW – 1, if necessary |                                           |     |      |      |     |     |      |            |     |           |           |           |          |

- Notes: 1. DM must be driven low all the time. DQS, /DQS are used according to read commands, otherwise FLOATING.  
2. Burst sequence driven on each DQ signal by read command. Outside burst operation, DQ signals are FLOATING.  
3. BA: BA0 to BA2.  
4. Am: m means Most Significant Bit (MSB) of Row address

## 2. Electrical Specifications

### 2.1 DC Characteristics

**Table 16: DC Characteristics 1 (VDD, VDDQ = 1.283V to 1.45V)**

| Parameter                                       | Symbol | Data rate<br>(Mbps) | X8(max) | x16(max) | unit | Notes       |
|-------------------------------------------------|--------|---------------------|---------|----------|------|-------------|
| Operating current<br>(ACT-PRE)                  | IDD0   | 1333                | 43      | 46       | mA   |             |
|                                                 |        | 1600                | 45      | 47       |      |             |
|                                                 |        | 1866                | 47      | 49       |      |             |
|                                                 |        | 2133                | 49      | 51       |      |             |
| Operating current<br>(ACT-RD-PRE)               | IDD1   | 1333                | 57      | 65       | mA   |             |
|                                                 |        | 1600                | 59      | 67       |      |             |
|                                                 |        | 1866                | 62      | 70       |      |             |
|                                                 |        | 2133                | 65      | 73       |      |             |
| Precharge power-down<br>standby current         | IDD2P0 | 1333                | 7       | 11       | mA   | SlowPD Exit |
|                                                 |        | 1600                | 7       | 11       |      |             |
|                                                 |        | 1866                | 7       | 11       |      |             |
|                                                 |        | 2133                | 7       | 11       |      |             |
|                                                 | IDD2P1 | 1333                | 10      | 14       | mA   | FastPD Exit |
|                                                 |        | 1600                | 12      | 14       |      |             |
|                                                 |        | 1866                | 14      | 14       |      |             |
|                                                 |        | 2133                | 16      | 14       |      |             |
| Precharge standby current                       | IDD2N  | 1333                | 20      | 22       | mA   |             |
|                                                 |        | 1600                | 22      | 22       |      |             |
|                                                 |        | 1866                | 24      | 22       |      |             |
|                                                 |        | 2133                | 26      | 22       |      |             |
| Precharge standby<br>ODT current                | IDD2NT | 1333                | 24      | 34       | mA   |             |
|                                                 |        | 1600                | 26      | 35       |      |             |
|                                                 |        | 1866                | 28      | 37       |      |             |
|                                                 |        | 2133                | 30      | 39       |      |             |
| Precharge quiet standby<br>current              | IDD2Q  | 1333                | 20      | 21       | mA   |             |
|                                                 |        | 1600                | 22      | 21       |      |             |
|                                                 |        | 1866                | 24      | 21       |      |             |
|                                                 |        | 2133                | 26      | 21       |      |             |
| Active power-down current<br>(Always fast exit) | IDD3P  | 1333                | 22      | 21       | mA   |             |
|                                                 |        | 1600                | 24      | 21       |      |             |
|                                                 |        | 1866                | 26      | 21       |      |             |
|                                                 |        | 2133                | 28      | 21       |      |             |
| Active standby current                          | IDD3N  | 1333                | 26      | 34       | mA   |             |
|                                                 |        | 1600                | 28      | 35       |      |             |
|                                                 |        | 1866                | 30      | 37       |      |             |
|                                                 |        | 2133                | 32      | 39       |      |             |
| Operating current<br>(Burst read operating)     | IDD4R  | 1333                | 133     | 110      | mA   |             |
|                                                 |        | 1600                | 143     | 130      |      |             |
|                                                 |        | 1866                | 153     | 150      |      |             |
|                                                 |        | 2133                | 163     | 170      |      |             |
| Operating current<br>(Burst write operating)    | IDD4W  | 1333                | 133     | 122      | mA   |             |
|                                                 |        | 1600                | 143     | 141      |      |             |
|                                                 |        | 1866                | 153     | 159      |      |             |
|                                                 |        | 2133                | 163     | 176      |      |             |
| Burst refresh current                           | IDD5B  | 1333                | 226     | 151      | mA   |             |
|                                                 |        | 1600                | 233     | 152      |      |             |
|                                                 |        | 1866                | 240     | 153      |      |             |
|                                                 |        | 2133                | 247     | 154      |      |             |
| All bank interleave read<br>current             | IDD7   | 1333                | 168     | 174      | mA   |             |
|                                                 |        | 1600                | 178     | 197      |      |             |
|                                                 |        | 1866                | 188     | 221      |      |             |
|                                                 |        | 2133                | 198     | 246      |      |             |
| RESET low current                               | IDD8   | 1333                | IDD2P+2 | 10       | mA   |             |
|                                                 |        | 1600                |         | 10       |      |             |
|                                                 |        | 1866                |         | 10       |      |             |
|                                                 |        | 2133                |         | 10       |      |             |

**Table 17: Self-Refresh Current (VDD, VDDQ = 1.283V to 1.45V)**

| Parameter                                             | Symbol | X8(max) | X16(max) | unit | Notes    |
|-------------------------------------------------------|--------|---------|----------|------|----------|
| Self-refresh current<br>normal temperature range      | IDD6   | 10      | 11       | mA   | Max      |
| Self-refresh current<br>extended temperature<br>range | IDD6ET | 14      | 12       | mA   | Max@95'C |

## 2.2 Pin Capacitance

**Table 18: Pin Capacitance [DDR3L-1333 to 2133] (Operating Temperature = 25°C, VDD, VDDQ = 1.283V to 1.45V)**

| Parameter                                                       | Symbol      | DDR3L-1333 |      | DDR3L-1600 |      | DDR3L-1866 |      | DDR3L-2133 |      | Units | Notes   |
|-----------------------------------------------------------------|-------------|------------|------|------------|------|------------|------|------------|------|-------|---------|
|                                                                 |             | Min        | Max  | Min        | Max  | Min        | Max  | Min        | Max  |       |         |
| Input/output                                                    | CIO         | 1.4        | 2.4  | 1.4        | 2.3  | 1.4        | 2.2  | 1.4        | 2.1  | pF    | 1,2     |
| Input capacitance, CK and /CK                                   | CCK         | 0.8        | 1.4  | 0.8        | 1.4  | 0.8        | 1.3  | 0.8        | 1.3  | pF    | 2       |
| Input capacitance delta, CK and /CK                             | CDCK        | 0          | 0.15 | 0          | 0.15 | 0          | 0.15 | 0          | 0.15 | pF    | 2, 3    |
| Input/output capacitance delta, DQS and /DQS                    | CDDQS       | 0          | 0.15 | 0          | 0.15 | 0          | 0.15 | 0          | 0.15 | pF    | 2, 4    |
| Input capacitance, (control, address, command, input-only pins) | CI          | 0.75       | 1.3  | 0.75       | 1.3  | 0.75       | 1.2  | 0.75       | 1.2  | pF    | 2, 5    |
| Input capacitance delta, (All control input-only pins)          | CDI_CTRL    | -0.4       | 0.2  | -0.4       | 0.2  | -0.4       | 0.2  | -0.4       | 0.2  | pF    | 2, 6, 7 |
| Input capacitance delta, (All address/command input-only pins)  | CDI_ADD_CMD | -0.4       | 0.4  | -0.4       | 0.4  | -0.4       | 0.4  | -0.4       | 0.4  | pF    | 2, 8, 9 |
| Input/output capacitance delta, DQ,DM, DQS, /DQS, TDQS, /TDQS   | CDIO        | -0.5       | 0.3  | -0.5       | 0.3  | -0.5       | 0.3  | -0.5       | 0.3  | pF    | 2, 10   |
| Input/output capacitance of ZQ pin                              | CZQ         | –          | 3    | –          | 3    | –          | 3    | –          | 3    | pF    | 2, 11   |

- Notes: 1. Although the DM, TDQS and /TDQS pins have different functions, the loading matches DQ and DQS.  
2. VDD, VDDQ, VSS, VSSQ applied and all other pins floating (except the pin under test, CKE, /RESET and ODT as necessary). VDD = VDDQ = 1.5V, VBIAS=VDD/2 and on-die termination off.  
3. Absolute value of CCK-C/CK.  
4. Absolute value of CIO(DQS)-CIO(/DQS).  
5. CI applies to ODT, /CS, CKE, A0-A14, BA0-BA2, /RAS, /CAS and /WE.  
6. CDI\_CTRL applies to ODT, /CS and CKE.  
7.  $CDI\_CTRL = CI(CTRL) - 0.5 \times (CI(CLK) + CI(/CLK))$ .  
8. CDI\_ADD\_CMD applies to A0-A15, BA0-BA2, /RAS, /CAS and /WE.  
9.  $CDI\_ADD\_CMD = CI(ADD\_CMD) - 0.5 \times (CI(CLK) + CI(/CLK))$ .  
10.  $CDIO = CIO(DQ,DM) - 0.5 \times (CIO(DQS) + CIO(/DQS))$ .  
11. Maximum external load capacitance on ZQ pin: 5pF.

## 2.3 Standard SpeedBins

Table 19: DDR3L-1333 Speed Bins

| Speed Bin              |                    | DDR3L-1333             |           |      |                  |
|------------------------|--------------------|------------------------|-----------|------|------------------|
| CL-tRCD-tRP            |                    | 9-9-9                  |           |      |                  |
| Symbol                 | /CAS write latency | min                    | max       | Unit | Notes            |
| tAA                    |                    | 13.5<br>(13.125)       | 20        | ns   | 10               |
| tRCD                   |                    | 13.5<br>(13.125)       | —         | ns   | 10               |
| tRP                    |                    | 13.5<br>(13.125)       | —         | ns   | 10               |
| tRC                    |                    | 49.5<br>(49.125)       | —         | ns   | 10               |
| tRAS                   |                    | 36                     | 9 x tREFI | ns   | 5                |
| tCK(avg)@CL=5          | CWL=5              | 3.0                    | 3.3       | ns   | 1, 2, 3, 4, 5, 9 |
|                        | CWL=6, 7,          | Reserved               | Reserved  | ns   | 4                |
| tCK(avg)@CL=6          | CWL=5              | 2.5                    | 3.3       | ns   | 1, 2, 3, 5       |
|                        | CWL=6              | Reserved               | Reserved  | ns   | 1, 2, 3, 4, 5    |
|                        | CWL=7,             | Reserved               | Reserved  | ns   | 4                |
| tCK(avg)@CL=7          | CWL=5              | Reserved               | Reserved  | ns   | 4                |
|                        | CWL=6              | 1.875                  | < 2.5     | ns   | 1, 2, 3, 4, 5    |
|                        | CWL=7              | Reserved               | Reserved  | ns   | 1, 2, 3, 4, 5    |
| tCK(avg)@CL=8          | CWL=5              | Reserved               | Reserved  | ns   | 4                |
|                        | CWL=6              | 1.875                  | <2.5      | ns   | 1, 2, 3, 5       |
|                        | CWL=7              | Reserved               | Reserved  | ns   | 1, 2, 3, 4, 5    |
| tCK(avg)@CL=9          | CWL=5, 6           | Reserved               | Reserved  | ns   | 4                |
|                        | CWL=7              | 1.5                    | <1.875    | ns   | 1, 2, 3, 4, 5    |
| tCK(avg)@CL=10         | CWL=5, 6           | Reserved               | Reserved  | ns   | 4                |
|                        | CWL=7              | 1.5                    | <1.875    | ns   | 1, 2, 3, 5       |
| Supported CL settings  |                    | 5, 6, (7), 8, (9), 10, |           | nCK  |                  |
| Supported CWL settings |                    | 5, 6, 7,               |           | nCK  |                  |

**Table 20: DDR3L-1600 Speed Bins**

| Speed Bin              |                    | DDR3L-1600                |           |      |                  |
|------------------------|--------------------|---------------------------|-----------|------|------------------|
| CL-tRCD-tRP            |                    | 11-11-11                  |           |      |                  |
| Symbol                 | /CAS write latency | min                       | max       | Unit | Notes            |
| tAA                    |                    | 13.75<br>(13.125)         | 20        | ns   | 11               |
| tRCD                   |                    | 13.75<br>(13.125)         | —         | ns   | 11               |
| tRP                    |                    | 13.75<br>(13.125)         | —         | ns   | 11               |
| tRC                    |                    | 48.75<br>(48.125)         | —         | ns   | 11               |
| tRAS                   |                    | 35                        | 9 x tREFI | ns   | 9                |
| tCK(avg)@CL=5          | CWL=5              | 3.0                       | 3.3       | ns   | 1, 2, 3, 4, 6, 9 |
|                        | CWL=6, 7, 8        | Reserved                  | Reserved  | ns   | 4                |
| tCK(avg)@CL=6          | CWL=5              | 2.5                       | 3.3       | ns   | 1, 2, 3, 6       |
|                        | CWL=6              | Reserved                  | Reserved  | ns   | 1, 2, 3, 4, 6    |
|                        | CWL=7, 8           | Reserved                  | Reserved  | ns   | 4                |
| tCK(avg)@CL=7          | CWL=5              | Reserved                  | Reserved  | ns   | 4                |
|                        | CWL=6              | 1.875                     | < 2.5     | ns   | 1, 2, 3, 4, 6    |
|                        | CWL=7              | Reserved                  | Reserved  | ns   | 1, 2, 3, 4, 6    |
|                        | CWL=8              | Reserved                  | Reserved  | ns   | 4                |
| tCK(avg)@CL=8          | CWL=5              | Reserved                  | Reserved  | ns   | 4                |
|                        | CWL=6              | 1.875                     | <2.5      | ns   | 1, 2, 3, 6       |
|                        | CWL=7              | Reserved                  | Reserved  | ns   | 1, 2, 3, 4, 6    |
|                        | CWL=8              | Reserved                  | Reserved  | ns   | 1, 2, 3, 4       |
| tCK(avg)@CL=9          | CWL=5, 6           | Reserved                  | Reserved  | ns   | 4                |
|                        | CWL=7              | 1.5                       | <1.875    | ns   | 1, 2, 3, 4, 6    |
|                        | CWL=8              | Reserved                  | Reserved  | ns   | 1, 2, 3, 4       |
| tCK(avg)@CL=10         | CWL=5, 6           | Reserved                  | Reserved  | ns   | 4                |
|                        | CWL=7              | 1.5                       | <1.875    | ns   | 1, 2, 3, 6       |
|                        | CWL=8              | Reserved                  | Reserved  | ns   | 1, 2, 3, 4       |
| tCK(avg)@CL=11         | CWL=5, 6, 7        | Reserved                  | Reserved  | ns   | 4                |
|                        | CWL=8              | 1.25                      | <1.5      | ns   | 1, 2, 3          |
| Supported CL settings  |                    | 5, 6, (7), 8, (9), 10, 11 |           |      | nCK              |
| Supported CWL settings |                    | 5, 6, 7, 8                |           |      | nCK              |

Table 21: DDR3L-1866 Speed Bins

| Speed Bin              |                    | DDR3L-1866                   |           |      |               |
|------------------------|--------------------|------------------------------|-----------|------|---------------|
| CL-tRCD-tRP            |                    | 13-13-13                     |           |      |               |
| Symbol                 | /CAS write latency | min                          | max       | Unit | Notes         |
| tAA                    |                    | 13.91<br>(13.125)            | 20        | ns   |               |
| tRCD                   |                    | 13.91<br>(13.125)            | —         | ns   |               |
| tRP                    |                    | 13.91<br>(13.125)            | —         | ns   |               |
| tRC                    |                    | 47.91<br>(47.125)            | —         | ns   |               |
| tRAS                   |                    | 34                           | 9 x tREFI | ns   |               |
| tCK(avg)@CL=5          | CWL=5              | Reserved                     | Reserved  | ns   | 1, 2, 3, 4, 7 |
|                        | CWL=6, 7, 8, 9     | Reserved                     | Reserved  | ns   | 4,            |
| tCK(avg)@CL=6          | CWL=5              | 2.5                          | 3.3       | ns   | 1, 2, 3, 7    |
|                        | CWL=6              | Reserved                     | Reserved  | ns   | 1, 2, 3, 4, 7 |
|                        | CWL=7, 8, 9        | Reserved                     | Reserved  | ns   | 4             |
| tCK(avg)@CL=7          | CWL=5              | Reserved                     | Reserved  | ns   | 4             |
|                        | CWL=6              | 1.875                        | < 2.5     | ns   | 1, 2, 3, 4, 7 |
|                        | CWL=7, 8, 9        | Reserved                     | Reserved  | ns   | 4             |
| tCK(avg)@CL=8          | CWL=5              | Reserved                     | Reserved  | ns   | 4             |
|                        | CWL=6              | 1.875                        | < 2.5     | ns   | 1, 2, 3, 7    |
|                        | CWL=7              | Reserved                     | Reserved  | ns   | 1, 2, 3, 4, 7 |
|                        | CWL=8,9            | Reserved                     | Reserved  | ns   | 4             |
| tCK(avg)@CL=9          | CWL=5, 6           | Reserved                     | Reserved  | ns   | 4             |
|                        | CWL=7              | 1.5                          | < 1.875   | ns   | 1, 2, 3, 4, 7 |
|                        | CWL=8              | Reserved                     | Reserved  | ns   | 4             |
|                        | CWL=9              | Reserved                     | Reserved  | ns   | 1, 2, 3, 4, 7 |
| tCK(avg)@CL=10         | CWL=5, 6           | Reserved                     | Reserved  | ns   | 4             |
|                        | CWL=7              | 1.5                          | < 1.875   | ns   | 1, 2, 3, 7    |
|                        | CWL=8              | Reserved                     | Reserved  | ns   | 1, 2, 3, 4, 7 |
| tCK(avg)@CL=11         | CWL=5, 6, 7        | Reserved                     | Reserved  | ns   | 4             |
|                        | CWL=8              | 1.25                         | < 1.5     | ns   | 1, 2, 3, 4, 7 |
|                        | CWL=9              | Reserved                     | Reserved  | ns   | 1, 2, 3, 4    |
| tCK(avg)@CL=12         | CWL=5, 6, 7, 8     | Reserved                     | Reserved  | ns   | 4             |
|                        | CWL=9              | Reserved                     | Reserved  | ns   | 1, 2, 3, 4    |
| tCK(avg)@CL=13         | CWL=5, 6, 7, 8     | Reserved                     | Reserved  | ns   | 4             |
|                        | CWL=9              | 1.07                         | < 1.25    | ns   | 1, 2, 3       |
| Supported CL settings  |                    | 6, 8, 10, 13, (7), (9), (11) |           | nCK  |               |
| Supported CWL settings |                    | 5, 6, 7, 8, 9                |           | nCK  |               |

**Table 22: DDR3L-2133 Speed Bins**

| Speed Bin              |                    | DDR3L-2133               |           |      |               |
|------------------------|--------------------|--------------------------|-----------|------|---------------|
| CL-tRCD-tRP            |                    | 14-14-14                 |           |      |               |
| Symbol                 | /CAS write latency | min                      | max       | Unit | Notes         |
| tAA                    |                    | 13.09                    | 20        | ns   |               |
| tRCD                   |                    | 13.09                    | —         | ns   |               |
| tRP                    |                    | 13.09                    | —         | ns   |               |
| tRC                    |                    | 46.09                    | —         | ns   |               |
| tRAS                   |                    | 33.0                     | 9 x tREFI | ns   |               |
| tCK(avg)@CL=5          | CWL=6,7, 8, 9,10   | Reserved                 | Reserved  | ns   | 1, 2, 3, 4, 8 |
| tCK(avg)@CL=6          | CWL=5              | 2.5                      | 3.3       | ns   | 1, 2, 3, 8    |
|                        | CWL=6              | Reserved                 | Reserved  | ns   | 1, 2, 3, 4, 8 |
|                        | CWL=7, 8, 9,10     | Reserved                 | Reserved  | ns   | 4             |
| tCK(avg)@CL=7          | CWL=5              | Reserved                 | Reserved  | ns   | 4             |
|                        | CWL=6              | 1.875                    | < 2.5     | ns   | 1, 2, 3, 8    |
|                        | CWL=7              | Reserved                 | Reserved  | ns   | 1, 2, 3, 4, 8 |
|                        | CWL=8, 9,10        | Reserved                 | Reserved  | ns   | 4             |
| tCK(avg)@CL=8          | CWL=5              | Reserved                 | Reserved  | ns   | 4             |
|                        | CWL=6              | 1.875                    | < 2.5     | ns   | 1, 2, 3, 8    |
|                        | CWL=7              | Reserved                 | Reserved  | ns   | 1, 2, 3, 4, 8 |
|                        | CWL=8, 9,10        | Reserved                 | Reserved  | ns   | 4             |
| tCK(avg)@CL=9          | CWL=5, 6           | Reserved                 | Reserved  | ns   | 4             |
|                        | CWL=7              | 1.5                      | < 1.875   | ns   | 1, 2, 3, 8    |
|                        | CWL=8              | Reserved                 | Reserved  | ns   | 1, 2, 3, 4, 8 |
|                        | CWL=9,10           | Reserved                 | Reserved  | ns   | 4             |
| tCK(avg)@CL=10         | CWL=5, 6           | Reserved                 | Reserved  | ns   | 4             |
|                        | CWL=7              | 1.5                      | < 1.875   | ns   | 1, 2, 3, 8    |
|                        | CWL=8, 9           | Reserved                 | Reserved  | ns   | 1, 2, 3, 4, 8 |
|                        | CWL=10             | Reserved                 | Reserved  | ns   | 4             |
| tCK(avg)@CL=11         | CWL=5, 6, 7        | Reserved                 | Reserved  | ns   | 4             |
|                        | CWL=8              | 1.25                     | < 1.5     | ns   | 1, 2, 3, 8    |
|                        | CWL=9              | Reserved                 | Reserved  | ns   | 1, 2, 3, 4, 8 |
|                        | CWL=10             | Reserved                 | Reserved  | ns   | 1, 2, 3, 4, 8 |
| tCK(avg)@CL=12         | CWL=5, 6, 7, 8     | Reserved                 | Reserved  | ns   | 4             |
|                        | CWL=9              | Reserved                 | Reserved  | ns   | 1, 2, 3, 4, 8 |
|                        | CWL=10             | Reserved                 | Reserved  | ns   | 1, 2, 3, 4    |
| tCK(avg)@CL=13         | CWL=5, 6, 7, 8     | Reserved                 | Reserved  | ns   | 4             |
|                        | CWL=9              | 1.07                     | < 1.25    | ns   | 1, 2, 3, 8    |
|                        | CWL=10             | Reserved                 | Reserved  | ns   | 1, 2, 3, 4    |
| tCK(avg)@CL=14         | CWL=5, 6, 7, 8,9   | Reserved                 | Reserved  | ns   | 4             |
|                        | CWL=10             | 0.938                    | < 1.07    | ns   | 1, 2, 3, 5    |
| Supported CL settings  |                    | 5,6,7,8,9,10,11,12,13,14 |           | nCK  |               |
| Supported CWL settings |                    | 5, 6, 7, 8, 9,10         |           | nCK  |               |

## Electrical Characteristics & AC Timing for DDR3L-1600 to DDR3L-2133 (Cont'd)

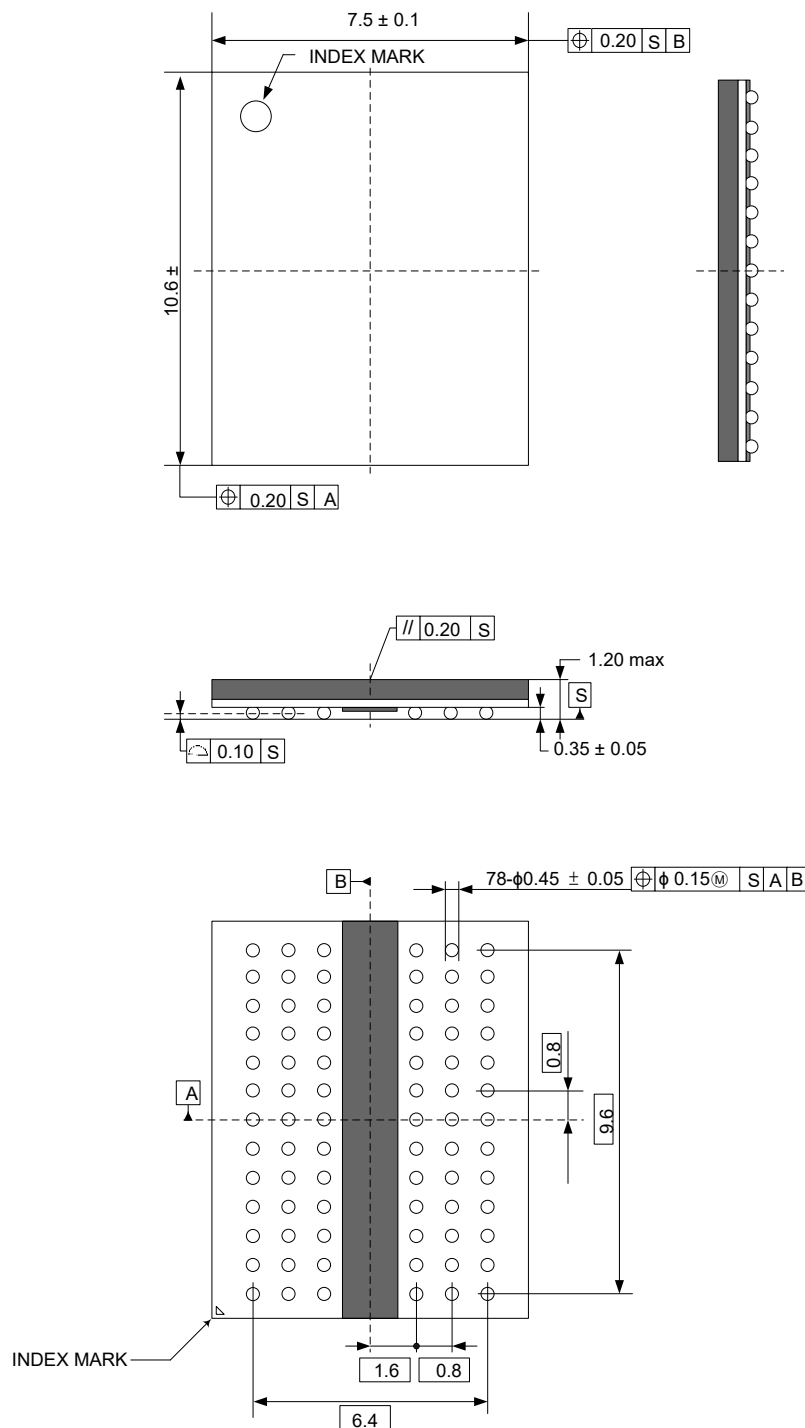
### Standard Speed Bins (Cont'd)

- NOTE 1.** The CL setting and CWL setting result in tCK(AVG).MIN and tCK(AVG).MAX requirements. When making a selection of tCK(AVG), both need to be fulfilled: Requirements from CL setting as well as requirements from CWL setting.
- NOTE 2.** tCK(AVG).MIN limits: Since CAS Latency is not purely analog - data and strobe output are synchronized by the DLL - all possible intermediate frequencies may not be guaranteed. An application should use the next smaller JEDEC standard tCK(AVG) value (3.0, 2.5, 1.875, 1.5, 1.25, 1.07, or 0.938 ns) when calculating  $CL [nCK] = tAA [ns] / tCK(AVG) [ns]$ , rounding up to the next 'Supported CL', where tCK(AVG) = 3.0 ns should only be used for CL = 5 calculation.
- NOTE 3.** tCK(AVG).MAX limits: Calculate  $tCK(AVG) = tAA.MAX / CL \text{ SELECTED}$  and round the resulting tCK(AVG) down to the next valid speed bin (i.e. 3.3ns or 2.5ns or 1.875 ns or 1.5 ns or 1.25 ns or 1.07 ns or 0.938 ns). This result is tCK(AVG).MAX corresponding to CL SELECTED.
- NOTE 4.** 'Reserved' settings are not allowed. User must program a different value.
- NOTE 5.** Any DDR3L-1333 speed bin also supports functional operation at lower frequencies as shown in the table which are not subject to Production Tests but verified by Design/Characterization.
- NOTE 6.** Any DDR3L-1600 speed bin also supports functional operation at lower frequencies as shown in the table which are not subject to Production Tests but verified by Design/Characterization.
- NOTE 7.** Any DDR3L-1866 speed bin also supports functional operation at lower frequencies as shown in the table which are not subject to Production Tests but verified by Design/Characterization.
- NOTE 8.** Any DDR3L-2133 speed bin also supports functional operation at lower frequencies as shown in the table which are not subject to Production Tests but verified by Design/Characterization.
- NOTE 9.** For CL5 support, refer to DIMM SPD information. DRAM is required to support CL5. CL5 is not mandatory in SPD coding.
- NOTE 10.** tREFI depends on operating commercial temperature and industrial temperature.
- NOTE 11.** For devices supporting optional down binning to CL=11 and CL=9, tAA/tRCD/tRPmin must be 13.125ns. SPD setting must be programed to match.

### 3. Package Drawing

#### 3.1 78-ball FBGA

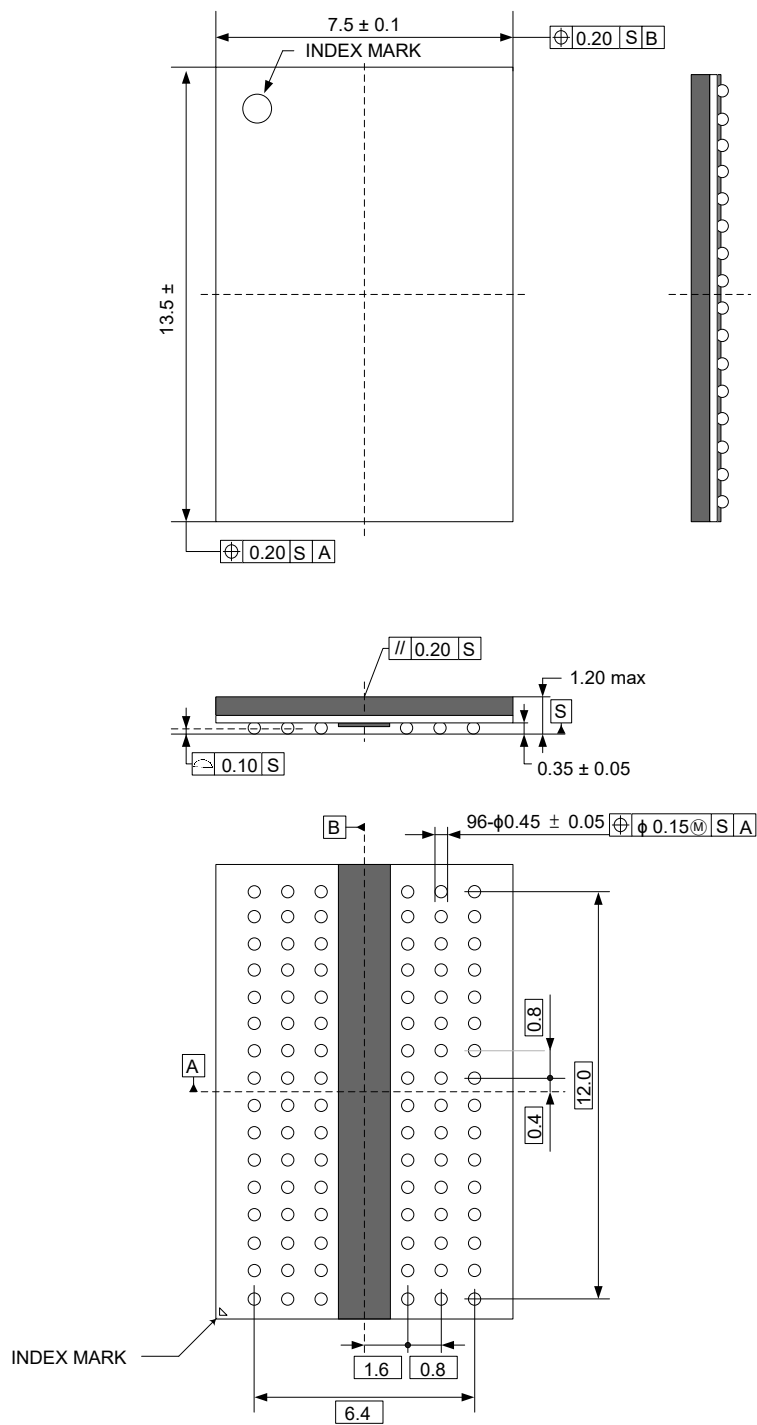
Solder ball: Lead free (Sn-Ag-Cu)



### 3.2 96-ball FBGA

Solder ball: Lead free (Sn-Ag-Cu)

Unit: mm



### ① PRECAUTION AGAINST ESD FOR MOS DEVICES

Exposing the MOS devices to a strong electric field can cause destruction of the gate oxide and ultimately degrade the MOS devices operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it, when once it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. MOS devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. MOS devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor MOS devices on it.

### ② HANDLING OF UNUSED INPUT PINS FOR CMOS DEVICES

No connection for CMOS devices input pins can be a cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. The unused pins must be handled in accordance with the related specifications.

### ③ STATUS BEFORE INITIALIZATION OF MOS DEVICES

Power-on does not necessarily define initial status of MOS devices. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the MOS devices with reset function have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. MOS devices are not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for MOS devices having reset function.

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#### [Usage environment]

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#### Example:

- 1) Usage in liquids, including water, oils, chemicals and organic solvents.
- 2) Usage in exposure to direct sunlight or the outdoors, or in dusty places.
- 3) Usage involving exposure to significant amounts of corrosive gas, including sea air, CL2, H2S, NH3, SO2, and NOx.
- 4) Usage in environments with static electricity, or strong electromagnetic waves or radiation.
- 5) Usage in places where dew forms.
- 6) Usage in environments with mechanical vibration, impact, or stress.
- 7) Usage near heating elements, igniters, or flammable items.

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